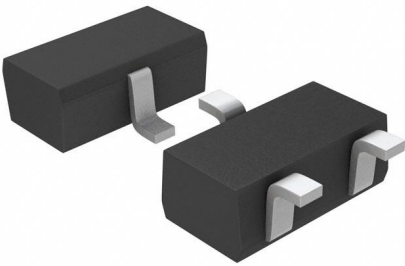


UNR31A100L Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

| | |
|------------------------------|--|
| DiGi Electronics Part Number | UNR31A100L-DG |
| Manufacturer | Panasonic Electronic Components |
| Manufacturer Product Number | UNR31A100L |
| Description | TRANS PREBIAS PNP 50V SSSMINI3 |
| Detailed Description | Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased 50 V 80 mA 80 MHz 100 mW Surface Mount SSSM ini3-F1 |



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

UNR31A100L

Series:

-

Transistor Type:

PNP - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

50 V

Resistor - Emitter Base (R2):

10 kOhms

Vce Saturation (Max) @ Ib, Ic:

250mV @ 300µA, 10mA

Frequency - Transition:

80 MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SSSMini3-F1

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

80 mA

Resistor - Base (R1):

10 kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

35 @ 5mA, 10V

Current - Collector Cutoff (Max):

500nA

Power - Max:

100 mW

Package / Case:

SOT-723

Base Product Number:

UNR31

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0095

ECCN:

EAR99

UNR31A1

Silicon PNP epitaxial planar type

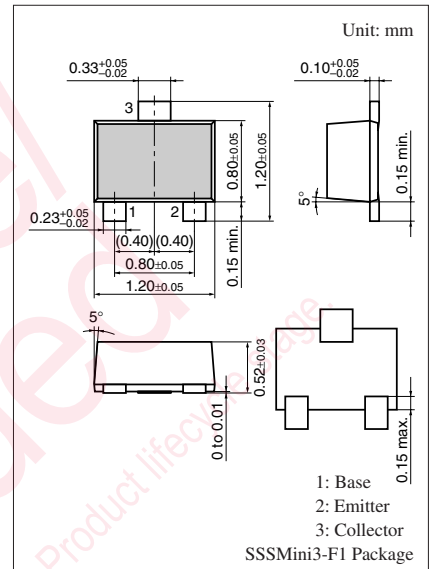
For digital circuits

■ Features

- Suitable for high-density mounting and downsizing of the equipment
- Contribute to low power consumption

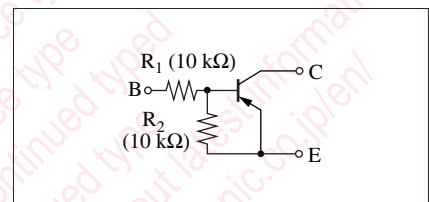
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|-----------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | -50 | V |
| Collector-emitter voltage (Base open) | V_{CEO} | -50 | V |
| Collector current | I_C | -80 | mA |
| Total power dissipation | P_T | 100 | mW |
| Junction temperature | T_j | 125 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +125 | $^\circ\text{C}$ |



Marking Symbol: CE

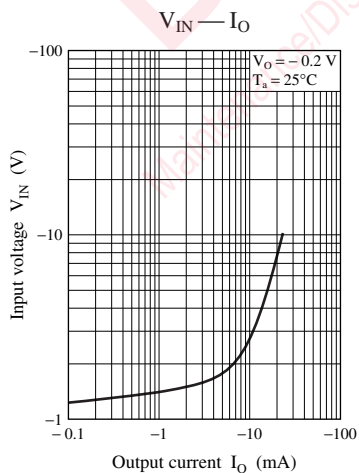
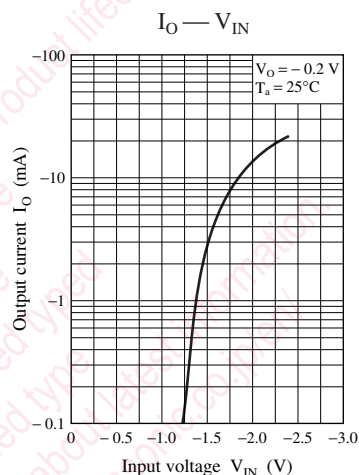
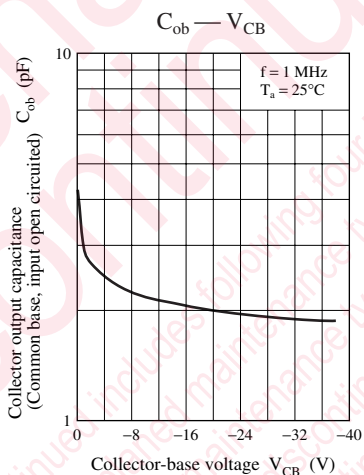
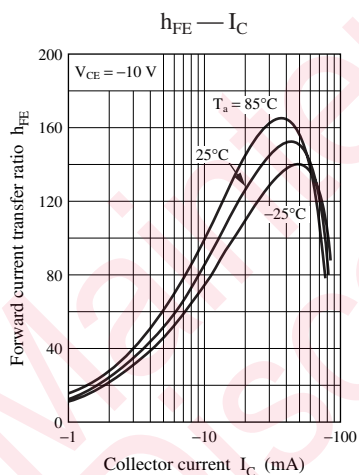
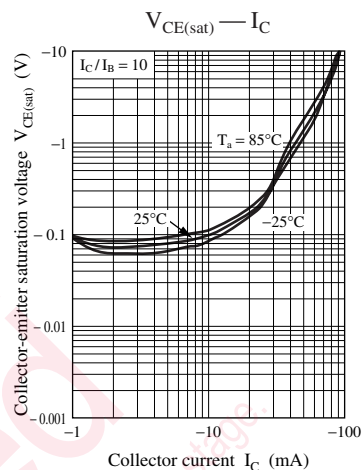
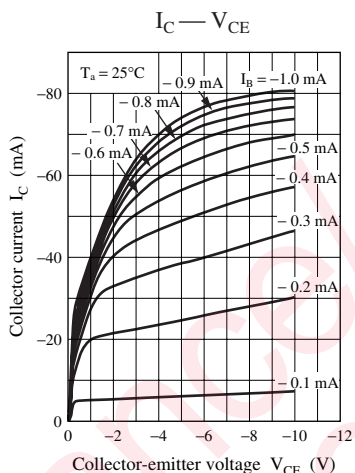
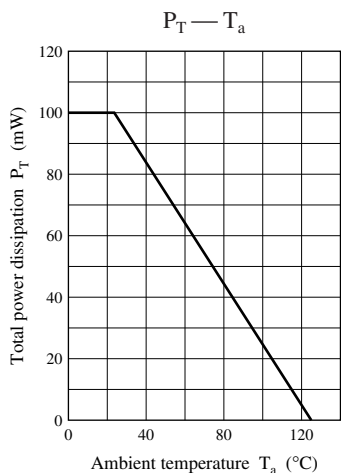
Internal Connection



■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|---------------|--|------|-----|-------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = -10 \mu\text{A}, I_E = 0$ | -50 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_C = -2 \text{ mA}, I_B = 0$ | -50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = -50 \text{ V}, I_E = 0$ | | | -0.1 | μA |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{CE} = -50 \text{ V}, I_B = 0$ | | | -0.5 | μA |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = -6 \text{ V}, I_C = 0$ | | | -0.5 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$ | 35 | | | — |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$ | | | -0.25 | V |
| Output voltage high-level | V_{OH} | $V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | -4.9 | | | V |
| Output voltage low-level | V_{OL} | $V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | | | -0.2 | V |
| Input resistance | R_1 | | -30% | 10 | +30% | $\text{k}\Omega$ |
| Resistance ratio | R_1 / R_2 | | 0.8 | 1.0 | 1.2 | — |
| Transition frequency | f_T | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$ | | 80 | | MHz |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



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